

DOCKET NO: 210093US2S

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF :
SHOTARO UCHIDA : EXAMINER: IM, J.
SERIAL NO: 09/891,316 :
FILED: JUNE 27, 2001 : GROUP ART UNIT: 2811
FOR: SEMICONDUCTOR DEVICE :
MANUFACTURING METHOD AND
SEMICONDUCTOR DEVICE
MANUFACTURED THEREBY

10/B (AE)
7/2/3
Cusler
Guth
Min 1h
8/2/3

AMENDMENT UNDER 37 C.F.R. § 1.116

COMMISSIONER FOR PATENTS
ALEXANDRIA, VIRGINIA 22313

SIR:

In response to the Office Action of May 6, 2003, please amend the above-identified application as follows:

IN THE CLAIMS

Please amend Claims 21 and 24 as follows:

21. (Amended) A semiconductor device comprising:

a transistor chip having a first main electrode and a gate electrode for a transistor on an upper surface of the transistor chip, a second main electrode on a bottom surface of the transistor chip, and a Schottky diode connected in parallel to the transistor;

a package base to which the second main electrode of the transistor chip is joined and connected;

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